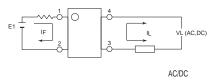
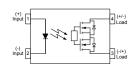
# **SUPSIC®**

#### **Parameter Symbol** Rating **Units** Load Voltage $V_{\mathsf{L}}$ 200 ٧ Load Current ΙL 0.40 Α 1.8 Ω On-Resistance Ron I/O Breakdown Voltage V/ıo 2500 Vrms







1. LED Anode

SOP-4

- 2. LED Cathode
- 3.4. Drain(MOS FET)

#### SOP-4

### SUPSiC PhotoRelays

- Long life (No limit on mechanical and electrical
- lifetime)Bounce-free switching
- Higher speed and high frequency switching
- Higher sensitivity (less power consumption)
- Immunity to EMI or RFI

- No have voltaic arc, bounce, and noise More
- resistant to vibration and impact AC or DC load
- switching
- Small package size

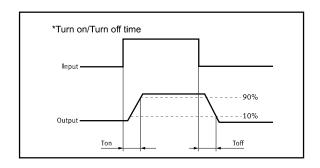
### **Applications**

- · Telecom/Datacom switching
- Multiplexers
- Meter reading systems
- Data acquisition
- Medical equipment
- Battery monitoring
- I/O Sub-Systems

- Robotics
- Aerospace
- Home/Safety security systems
- Process Control
- Energy Management
- Reed Relay EMR Replacement
- Programmable Controllers

#### **TPYES**

Category	Output Rating		Doolsome	Part No.	Packing Overtity	
	Load Voltage	Load Current	Package	Part No.	Packing Quantity	
AC/DC	200V	0.40A	SOP-4	GAQY237S	2000pcs /reel	





#### Absolute Maximum Ratings (Ta = 25°C)

	Item	Symbol	Va <b>l</b> ue	Units	Note	
	Continuous LED Current		50	mA		
Input	Peak LED Current	Ігр	1000	mA	f=100Hz, duty=1%	
	LED Reverse Voltage	VR	5	V		
	Input Power Dissipation	Pın	75	mW		
	Load Voltage	V∟	200	V(AC peak or DC)		
	Load Current	l.	0.40	Α		
Output	Peak Load Current	Peak	1.00	Α	100ms(1 pulse)	
	Output Power Dissipation	Pout	450	mW		
Total Power Dissipation		Р⊤	500	mW		
I/O Breakdown Voltage		V <sub>I/O</sub>	2500	Vrms	RH=60%, 1min	
Operating Temperature		Topr	-40 to 85	°C		
Storage Tem	perature	T <sub>stg</sub>	-40 to 100	°C		
Pin Soldering Temperature		T <sub>sol</sub>	260	°C	10 sec max.	

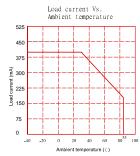
## Electrical Characteristics (Ta = 25°C)

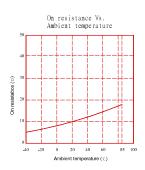
Item		Symbol	MIN.	TYP.	MAX.	Units	Conditions
	LED Forward Voltage			1.2	1.4	V	I⊧=10mA
	Operation LED Current	Fon		0.5	2.0	mA	
Input	Recovery LED Current	Foff		0.35	0.5	mA	
	Recovery LED Voltage	V <sub>Foff</sub>	0.7			٧	
	On-Resistance	Ron		1.8	3.5	Ω	I <sub>F</sub> =5mA,I <sub>L</sub> =Max Time to flow is within 1 sec.
Output	Off-State Leakage Current	Leak		0.1		uA	V <sub>L</sub> =Rating
	Output Capacitance	Cout		74		pF	V∟=0, f=1MHz
Transmis	Turn-On Time	Ton		0.05	0.2	ms	I⊧=5mA, I∟=Max
sion	Turn-Off Time	Toff		0.02	0.2	ms	
0	I/O Isolation Resistance	R <sub>I/O</sub>	10 <sup>10</sup>			Ω	DC500V
Coupled	I/O Capacitance	Cı/o		0.8	1.5	pF	f=1MHz

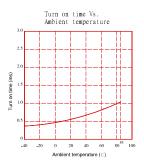
Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value): IF ≥5mA and ≤30mA

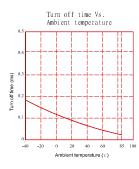


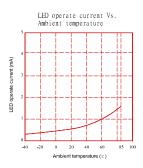
### **Engineering Data**

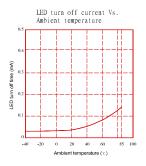


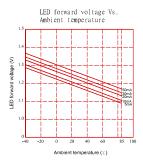


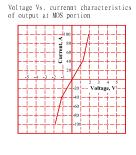


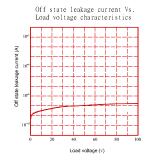


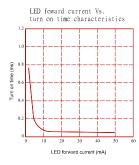


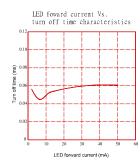


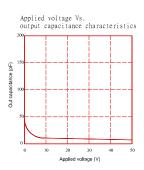










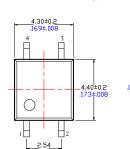




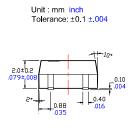
#### **Dimensions and Package**

# 

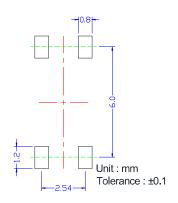
# 0.66±0.2 .026±.008 .036 .036 .036 .036



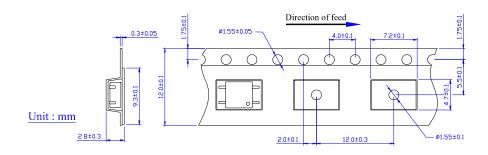
Surface mount terminal type

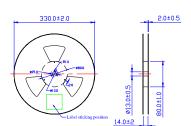


Recommended mounting pad (Top view)

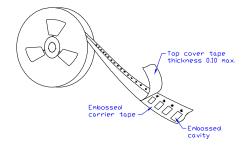


#### Tape dimensions





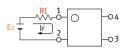
Dimensions of tape reel

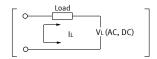




#### **Using Methods**

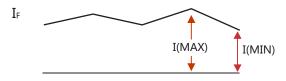
Examples of resistance value to control LED forward current (IF=5mA)





E1	R1 (Approx)			
3.3V	300 Ω			
5.0V	600 Ω			
12V	1.9KΩ			
24V	4.1K Ω			

LED forward current must be more than 5mA , at I(MIN) ,and less than 30mA , at I(MAX).



#### **Recommended Operating Conditions**

Please obey the following conditions to ensure proper device operation and resetting. Input LED current (Recommended value):

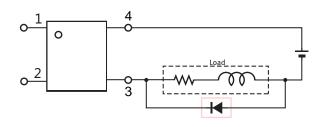
Characteristic	Symbol	Min	Тур.	Max	Unit
Forward current	lF	5.0	7.0	30	mA

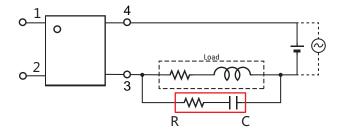
#### **Protection Circuit**

Output spike voltages:if an inductive load generates spike voltages which exceed heabsolute maximum rating, the spike voltage shall be limited.

Clamp diode is connected in parallel with the load. Absorb capacity with external diode.

CR Snubber is connected in parallel with the load. Absorb capacity with buffer capacity.





When adding diodes, buffer circuits (C-R), and other protections, they need to be installed near the MOS RELAY to be effective. Adding protection elements may result in a slow reset time, so adjust them according to the actual situation before use.

Note: When developing designs using this product, perform the expected performance of the equipment under the operating conditions recommended by the guidelines in this document. Continuous use under heavy loads (including, but not limited to, the application of high temperatures/current/voltage and significant changes in temperature, etc.) may result in deterioration of the reliability of this product.